

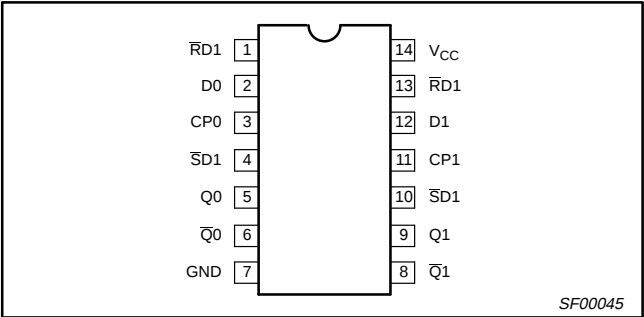
Dual D-type flip-flop

74ABT74

QUICK REFERENCE DATA

SYMBOL	PARAMETER	CONDITIONS $T_{amb} = 25^{\circ}\text{C}$; $GND = 0V$	TYPICAL	UNIT
t_{PLH} t_{PHL}	Propagation delay CPn to Qn, $\bar{Q}n$	$C_L = 50\text{pF}$; $V_{CC} = 5V$	3.0 2.5	ns
t_{OSLH} t_{OSHL}	Output to Output skew		0.5	ns
C_{IN}	Input capacitance	$V_I = 0V$ or V_{CC}	3	pF
I_{CC}	Total supply current	Outputs disabled; $V_{CC} = 5.5V$	50	μA

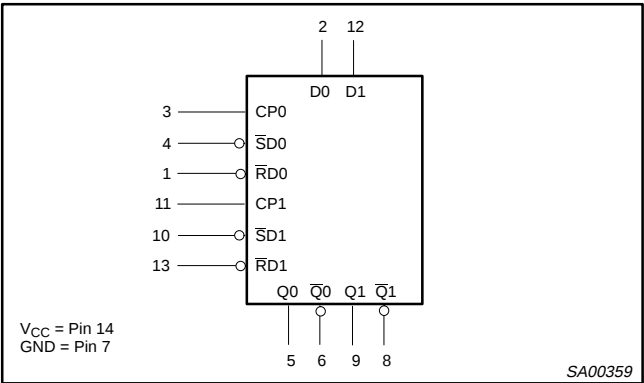
PIN CONFIGURATION



PIN DESCRIPTION

PIN NUMBER	SYMBOL	NAME AND FUNCTION
1, 2, 3, 4, 10, 11, 12, 13	$\bar{R}Dn$, Dn, CPn, $\bar{S}Dn$	Data inputs
5, 6, 8, 9	Qn, $\bar{Q}n$	Data outputs
7	GND	Ground (0V)
14	V_{CC}	Positive supply voltage

LOGIC SYMBOL



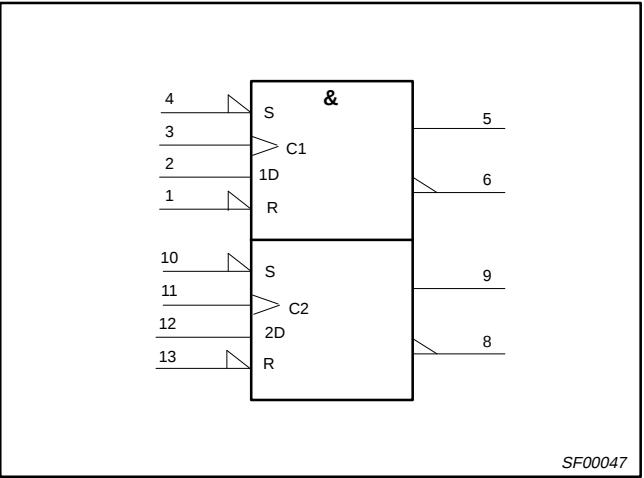
ORDERING INFORMATION

PACKAGES	TEMPERATURE RANGE	OUTSIDE NORTH AMERICA	NORTH AMERICA	DWG NUMBER
14-Pin Plastic DIP	-40°C to $+85^{\circ}\text{C}$	74ABT74 N	74ABT74 N	SOT27-1
14-Pin plastic SO	-40°C to $+85^{\circ}\text{C}$	74ABT74 D	74ABT74 D	SOT108-1
14-Pin Plastic SSOP Type II	-40°C to $+85^{\circ}\text{C}$	74ABT74 DB	74ABT74 DB	SOT337-1
14-Pin Plastic TSSOP Type I	-40°C to $+85^{\circ}\text{C}$	74ABT74 PW	74ABT74PW DH	SOT402-1

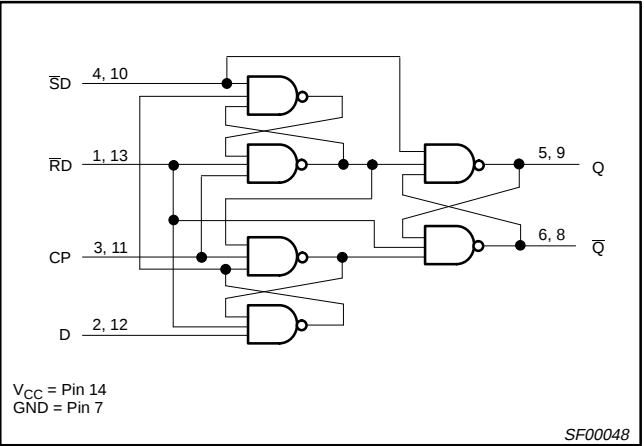
DESCRIPTION

The 74ABT74 is a dual positive edge-triggered D-type flip-flop featuring individual data, clock, set, and reset inputs; also true and complementary outputs. Set ($\bar{S}D$) and reset ($\bar{R}D$) are asynchronous active low inputs and operate independently of the clock input. When set and reset are inactive (high), data at the D input is transferred to the Q and $\bar{Q}$ outputs on the low-to-high transition of the clock. Data must be stable just one setup time prior to the low-to-high transition of the clock for predictable operation. Clock triggering occurs at a voltage level and is not directly related to the transition time of the positive-going pulse. Following the hold time interval, data at the D input may be changed without affecting the levels of the output.

LOGIC SYMBOL (IEEE/IEC)



LOGIC DIAGRAM



Dual D-type flip-flop

74ABT74

FUNCTION TABLE

INPUTS				OUTPUTS		OPERATING MODE
$\overline{SD}$	$\overline{RD}$	CP	D	Q	$\overline{Q}$	
L	H	X	X	H	L	Asynchronous set
H	L	X	X	L	H	Asynchronous reset
L	L	X	X	H	H	Undetermined*
H	H	$\uparrow$	h	H	L	Load "1"
H	H	$\uparrow$	l	L	H	Load "0"
H	H	$\uparrow$	X	NC	NC	Hold

NOTES:

H = High voltage level

h = High voltage level one setup time prior to low-to-high clock transition

L = Low voltage level

l = Low voltage level one setup time prior to low-to-high clock transition

NC = No change from the previous setup

X = Don't care

 $\uparrow$ = Low-to-high clock transition $\uparrow$ = Not low-to-high clock transition

* = This setup is unstable and will change when either set or reset return to the high level.

ABSOLUTE MAXIMUM RATINGS^{1, 2}

SYMBOL	PARAMETER	CONDITIONS	RATING	UNIT
V_{CC}	DC supply voltage		-0.5 to +7.0	V
I_{IK}	DC input diode current	$V_I < 0$	-18	mA
V_I	DC input voltage ³		-1.2 to +7.0	V
I_{OK}	DC output diode current	$V_O < 0$	-50	mA
V_{OUT}	DC output voltage ³	output in Off or High state	-0.5 to +5.5	V
I_{OUT}	DC output current	output in Low state	40	mA
T_{stg}	Storage temperature range		-65 to 150	°C

NOTES:

- Stresses beyond those listed may cause permanent damage to the device. These are stress ratings only and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.
- The performance capability of a high-performance integrated circuit in conjunction with its thermal environment can create junction temperatures which are detrimental to reliability. The maximum junction temperature of this integrated circuit should not exceed 150°C.
- The input and output voltage ratings may be exceeded if the input and output current ratings are observed.

RECOMMENDED OPERATING CONDITIONS

SYMBOL	PARAMETER	LIMITS		UNIT
		MIN	MAX	
V_{CC}	DC supply voltage	4.5	5.5	V
V_I	Input voltage	0	V_{CC}	V
V_{IH}	High-level input voltage	2.0		V
V_{IL}	Low-level input voltage		0.8	V
I_{OH}	High-level output current		-15	mA
I_{OL}	Low-level output current		20	mA
$\Delta t/\Delta v$	Input transition rise or fall rate	0	10	ns/V
T_{amb}	Operating free-air temperature range	-40	+85	°C

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DC ELECTRICAL CHARACTERISTICS

SYMBOL	PARAMETER	TEST CONDITIONS	LIMITS					UNIT
			T _{amb} = +25°C			T _{amb} = −40°C to +85°C		
			MIN	TYP	MAX	MIN	MAX	
V _{IK}	Input clamp voltage	V _{CC} = 4.5V; I _{IK} = −18mA		−0.9	−1.2		−1.2	V
V _{OH}	High-level output voltage	V _{CC} = 4.5V; I _{OH} = −15mA; V _I = V _{IL} or V _{IH}	2.5	2.9		2.5		V
V _{OL}	Low-level output voltage	V _{CC} = 4.5V; I _{OL} = 20mA; V _I = V _{IL} or V _{IH}		0.35	0.5		0.5	V
I _I	Input leakage current	V _{CC} = 5.5V; V _I = GND or 5.5V		±0.01	±1.0		±1.0	μA
I _{OFF}	Power-off leakage current	V _{CC} = 0.0V; V _O or V _I ≤ 4.5V		±5.0	±100		±100	μA
I _{CEX}	Output High leakage current	V _{CC} = 5.5V; V _O = 5.5V; V _I = GND or V _{CC}		5.0	50		50	μA
I _O	Output current ¹	V _{CC} = 5.5V; V _O = 2.5V	−50	−75	−180	−50	−180	mA
I _{CC}	Quiescent supply current	V _{CC} = 5.5V; V _I = GND or V _{CC}		2	50		50	μA
ΔI _{CC}	Additional supply current per input pin ²	V _{CC} = 5.5V; One data input at 3.4V, other inputs at V _{CC} or GND		0.25	500		500	μA

NOTES:

- Not more than one output should be tested at a time, and the duration of the test should not exceed one second.
- This is the increase in supply current for each input at 3.4V.
- For valid test results, data must not be loaded into the flip-flop or latch after applying the power.

AC ELECTRICAL CHARACTERISTICS

GND = 0V; $t_R = t_F = 2.5\text{ns}$; $C_L = 50\text{pF}$; $R_L = 500\Omega$

SYMBOL	PARAMETER	WAVEFORM	LIMITS					UNIT
			T _{amb} = +25°C V _{CC} = +5.0V			T _{amb} = −40°C to +85°C V _{CC} = +5.0V ±0.5V		
			MIN	TYP	MAX	MIN	MAX	
f _{MAX}	Maximum clock frequency	1	180	250		150		MHz
t _{PLH} t _{PHL}	Propagation delay CPn to Qn, Q̄n	1	1.0 1.0	3.0 2.5	4.2 3.5	1.0 1.0	4.7 4.0	ns
t _{PLH} t _{PHL}	Propagation delay Sn, R̄n to Qn, Q̄n	3	1.0 1.0	3.4 2.9	4.9 4.5	1.0 1.0	6.2 5.2	ns
t _{OSHL} t _{OSLH} ¹	Output to Output skew An or Bn to Yn	4		0.5	0.6		0.6	ns

NOTE:

- Skew is defined as the absolute value of the difference between the actual propagation delay for any two separate outputs of the same device. The specification applies to any outputs switching in the the same direction, either HIGH-to-LOW (t_{OSHL}) or LOW-to-HIGH (t_{OSLH}); parameter guaranteed by design.

AC SETUP REQUIREMENTS

GND = 0V; $t_R = t_F = 2.5\text{ns}$; $C_L = 50\text{pF}$; $R_L = 500\Omega$

SYMBOL	PARAMETER	WAVEFORM	LIMITS			UNIT
			$T_{amb} = +25^{\circ}\text{C}$ $V_{CC} = +5.0\text{V}$		$T_{amb} = -40^{\circ}\text{C to } +85^{\circ}\text{C}$ $V_{CC} = +5.0\text{V} \pm 0.5\text{V}$	
			MIN	TYP	MIN	
t_{su} (H) t_{su} (L)	Setup time, high or low Dn to CPn	1	2.6 2.4	1.4 1.4	2.6 2.4	ns
t_h (H) t_h (L)	Hold time, high or low Dn to CPn	1	0 0	-1.4 -1.4	0 0	ns
t_w (H) t_w (L)	CPn pulse width, high or low	1	1.7 1.7	1.0 1.0	2.1 2.1	ns
t_w (L)	$\overline{SDn}$, $\overline{RDn}$ pulse width, low	3	2.0	1.3	2.2	ns
t_{rec}	Recovery time $\overline{SDn}$, $\overline{RDn}$ to CPn	2	2.1	1.4	2.4	ns

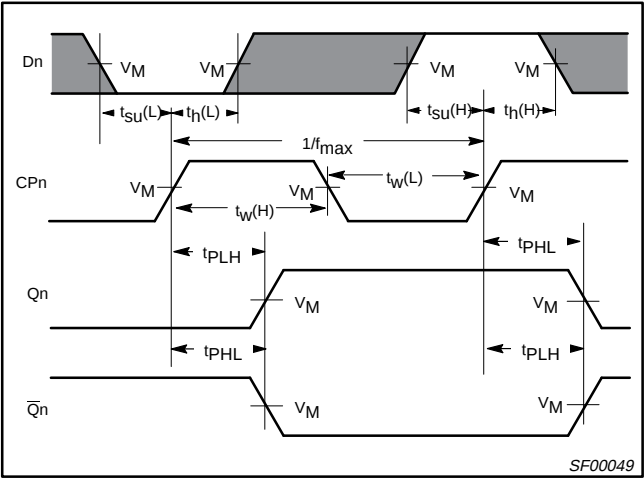
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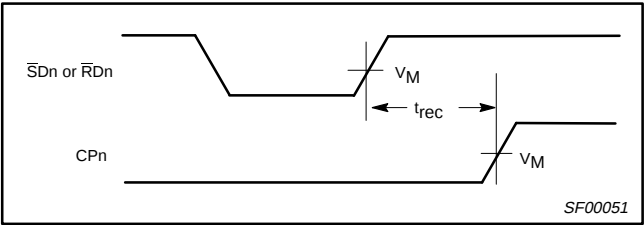
AC WAVEFORMS

$V_M = 1.5V$, $V_{IN} = GND$ to $3.0V$

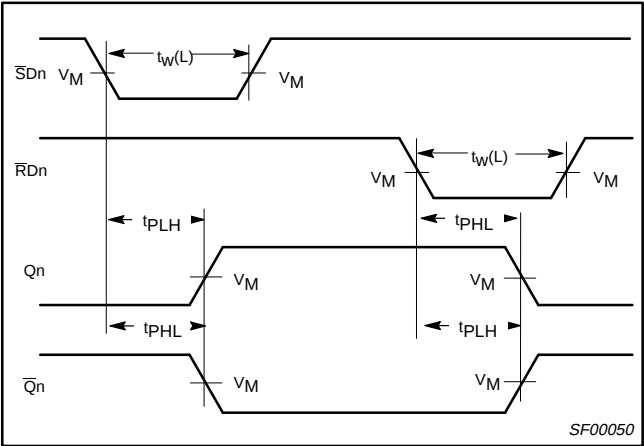
The shaded areas indicate when the input is permitted to change for predictable output performance



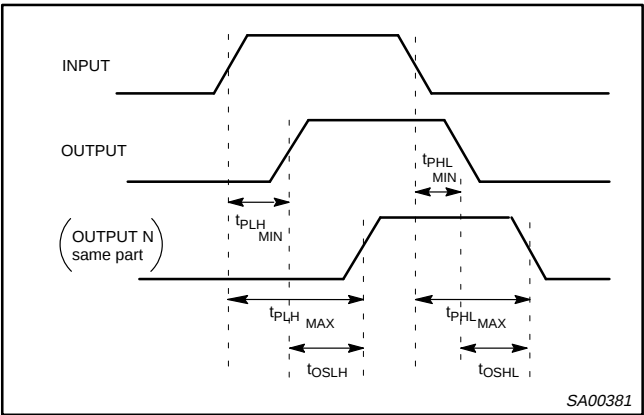
Waveform 1. Propagation delay for data to output, data setup time and hold times, and clock width, and maximum clock frequency



Waveform 2. Recovery time for set or reset to clock



Waveform 3. Propagation delay for set and reset to output, set and reset pulse width

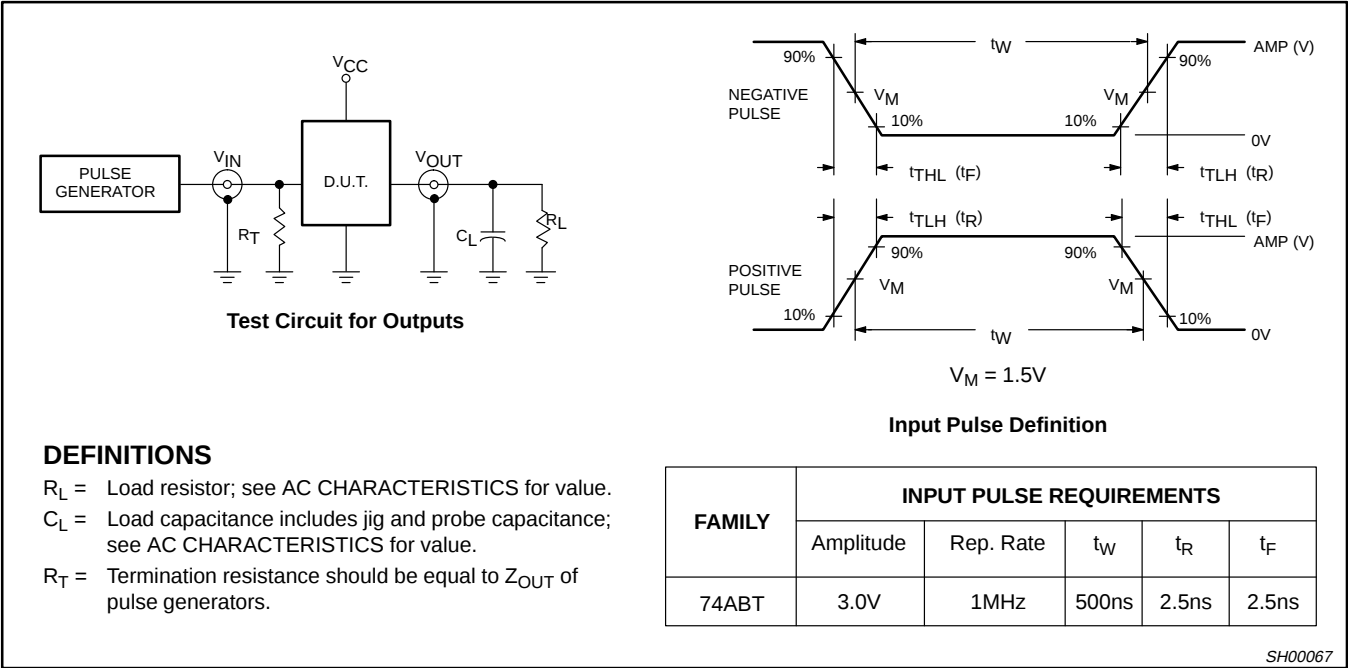


Waveform 4. Common edge skew

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TEST CIRCUIT AND WAVEFORMS





Компания «ЭлектроПласт» предлагает заключение долгосрочных отношений при поставках импортных электронных компонентов на взаимовыгодных условиях!

Наши преимущества:

- Оперативные поставки широкого спектра электронных компонентов отечественного и импортного производства напрямую от производителей и с крупнейших мировых складов;
- Поставка более 17-ти миллионов наименований электронных компонентов;
- Поставка сложных, дефицитных, либо снятых с производства позиций;
- Оперативные сроки поставки под заказ (от 5 рабочих дней);
- Экспресс доставка в любую точку России;
- Техническая поддержка проекта, помощь в подборе аналогов, поставка прототипов;
- Система менеджмента качества сертифицирована по Международному стандарту ISO 9001;
- Лицензия ФСБ на осуществление работ с использованием сведений, составляющих государственную тайну;
- Поставка специализированных компонентов (Xilinx, Altera, Analog Devices, Intersil, Interpoint, Microsemi, Aeroflex, Peregrine, Syfer, Eurofarad, Texas Instrument, Miteq, Cobham, E2V, MA-COM, Hittite, Mini-Circuits, General Dynamics и др.);

Помимо этого, одним из направлений компании «ЭлектроПласт» является направление «Источники питания». Мы предлагаем Вам помощь Конструкторского отдела:

- Подбор оптимального решения, техническое обоснование при выборе компонента;
- Подбор аналогов;
- Консультации по применению компонента;
- Поставка образцов и прототипов;
- Техническая поддержка проекта;
- Защита от снятия компонента с производства.



Как с нами связаться

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